

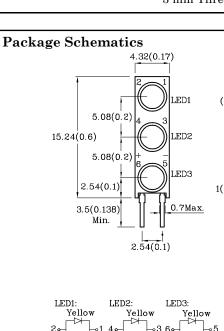
Part Number: XPZ3LUYG37M

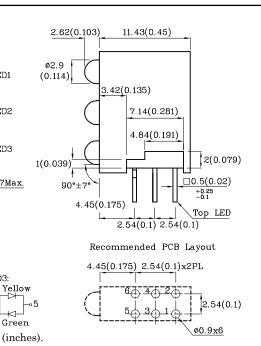
3 mm Three Position CBI Housing

Features

- Housing material: Type 66 Nylon
- \bullet Black casing provides superior contrast
- Housing UL rating: 94V-0
- \bullet Reliable & robust
- Custom color combinations available
- Halogen-free
- \bullet RoHS compliant







All dimensions are in millimeters (inches).
 Tolerance is ±0.25(0.01") unless otherwise noted.

Green

Notes:

3. Specifications are subject to change without notice.

Green

Absolute Maximum Ratings (T _A =25°C)		Yellow (GaAsP/ GaP)	Green (GaP)	Unit		
Forward Current	$\mathbf{I}_{\mathbf{F}}$	30	25	mA		
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	140	140	mA		
Power Dissipation	\mathbf{P}_{D}	75	62.5	mW		
Operating Temperature	$T_{\rm A}$	-40 ~	°C			
Storage Temperature	Tstg	-40 ~				
Lead Solder Temperature [2mm Below Package Base]	260°C For 3 Seconds					
Lead Solder Temperature [5mm Below Package Base]	260°C For 5 Seconds					

A Relative Humidity between 40% and 60% is recommended in ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)

Operating Characteristics (T _A =25°C)	Yellow (GaAsP/ GaP)	Green (GaP)	Unit	
Forward Voltage (Typ.) (I _F =20mA)	$V_{\rm F}$	2.1	2.2	V
Forward Voltage (Max.) (I _F =20mA)	$V_{\rm F}$	2.5	2.5	V
Wavelength of Peak Emission CIE127-2007* (Typ.) (I _F =20mA)	λP	590*	565*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) (I _F =20mA)	λD	588*	568*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =20mA)	$ riangle\lambda$	35	30	nm
Capacitance (Typ.) (V _F =0V, f=1MHz)	С	20	15	pF

Emitting Color	Emitting Material	Lens-color	Luminous Intensity CIE127-2007* (I _F =20mA) mcd		Wavelength CIE127-2007* nm λP	Viewing Angle 20 1/2
			min.	typ.		
Yellow XPZ3LUYG37M Green	GaAsP/GaP	– White Diffused –	4 *	7*	590*	60°
	GaP		6*	13*	565*	
	Color	Color Material Yellow GaAsP/GaP	Color Material Lens-color Yellow GaAsP/GaP White Diffused	Emitting Color Emitting Material Lens-color CIE127 (IF=2) min. Yellow GaAsP/GaP 4* White Diffused	Emitting Color Emitting Material Lens-color CIE127-2007* (IF=20mA) mcd Min. typ. Yellow GaAsP/GaP White Diffused	Emitting Color Emitting Material Lens-color CIE127-2007* (I _F =20mA) mcd CIE127-2007* nm λP Material Lens-color Material 0 Yellow GaAsP/GaP 4* 7* 590*

*Luminous intensity value and wavelength are in accordance with CIE127-2007 standards.

Feb 01,2022

XDSA7793 V6-Z Layout: Maggie L.



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09

Spatial Distribution

normalised

Luminous intensity

80 100

80 100 at $T^a = 25$

Luminous intensity normalised

at $T^a=25\ ^\circ\mathrm{C}$

15° 30°

2.5

2.0ç

1.5

1.0

0.5

0.0

2.5

2.0

1.5

1.0

0.5

0.0

-40

45° 60°

3 mm Three Position CBI Housing

15

1.0

0.5

0.0

75° 90°

-40 -20 0 20 40 60 80 100

-20 0 20 40 60 80

Ambient temperature (°C)

Luminous Intensity vs.

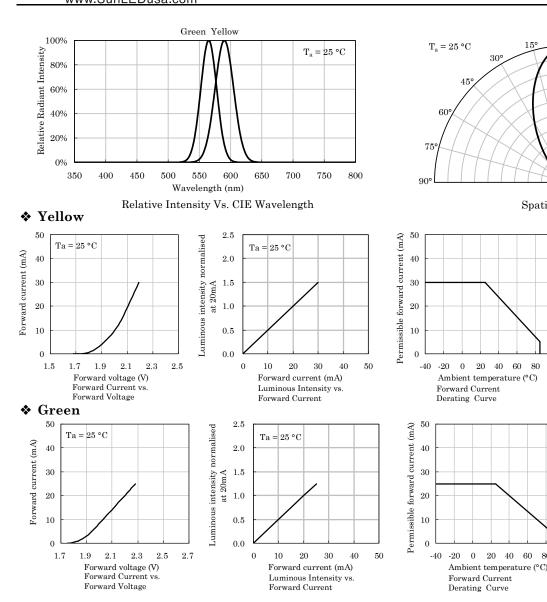
Ambient Temperature

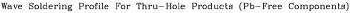
100

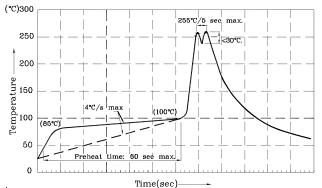
Ambient temperature (°C)

Luminous Intensity vs

Ambient Temperature







Notes:

Notes:
1. Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C
2. Peak wave soldering temperature between 245°C ~ 255°C for 3 sec
15 and maximum solder bath temperature between 245°C wave solder and the solder sector of the solder sector between 245°C wave maximum solder between 245°C wave solder and the solder sector between 245°C wave solder sector between 255°C for 3 sec

(5 sec max).

- (a) See final).
 (b) not apply stress to the epoxy resin while the temperature is above 85°C.
 (4) Fixtures should not incur stress on the component when mounting and during soldering process.
 (5) SAC 305 solder alloy is recommended.
 (6) No more than one wave soldering pass.

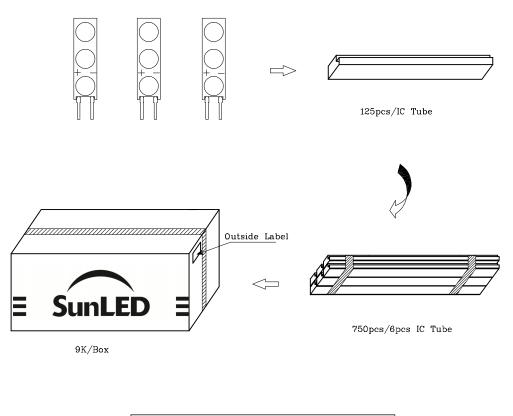
Remarks:

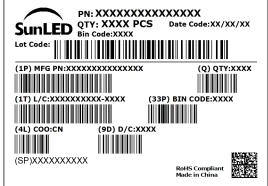
If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength),

- the typical accuracy of the sorting process is as follows:
- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V
- Note: Accuracy may depend on the sorting parameters.



PACKING & LABEL SPECIFICATIONS





TERMS OF USE

- 1. Data presented in this document reflect statistical figures and should be treated as technical reference only.
- 2. Contents within this document are subject to improvement and enhancement changes without notice.
- 3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet.
- User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
- 4. The product(s) described in this document are intended for electronic applications in which a person's life is not reliant upon the LED. Please consult with a SunLED representative for special applications where the LED may have a direct impact on a person's life.
- 5. The performance of the product(s) should be evaluated and verified by the customer to ensure it can meet the customer's application requirements.
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